NOTICE OF REVISION (NOR) (See MIL-STD-480 for instructions) This revision described below has been authorized for the document listed. DATE (YYMMDD) (YYMMDD) 93-04-07

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ORIGINATOR NAME AND ADDRESS Defense Electronics Supply Center	2. CAGE CODE 67268	3. NOR NO. 5962-R054-93
Dayton, Ohio 45444-5277	4. CAGE CODE 67268	5. DOCUMENT NO. 86008
6. TITLE OF DOCUMENT MICROCIRCUITS, LINEAR, HIGH-SPEED VOLTAGE COMPARATOR, MONOLITHIC SILICON	7. REVISION LETTER (Current) B 8. ECP NO. 86008ECP-1	(New) C

9. CONFIGURATION ITEM (OR SYSTEM) TO WHICH ECP APPLIES

10. DESCRIPTION OF REVISION

Sheet 1: Revisions ltr column; add "C"

Revisions description column; add "Changes in accordance with

NOR 5962-R054-93".

Revisions date column; add "93-04-07".

Revision level block; add "C".

Revision status of sheets; For sheets 1, 7, 8, 9, 11, and 12, add "C".

Sheet 7: TABLE I.

Propagation delay time test, device type 01, group A subgroups 9 and 11, min limit column,

delete 4.5 ns

and substitute 3.5 ns.

Propagation delay time and latch enable to output test, add footnote $\underline{5}/.$ Revision level block; add "C".

Sheet 8: TABLE I. Footnote $\frac{7}{}$.

Delete sentence "b" and substitute the following; "b. t_{PD+} on either output Q or Q is

performed."

Delete sentence "c" and substitute the following; "c. tpp_ on either output Q or Q is

performed."

Revision level block; add "C".

Sheet 9: FIGURE 1. Terminal connections. For case outline I, pin 6, delete "NC" and substitute "NC/HYSTERESIS".

For case outline E, pin 9, delete "NC" and substitute "NC/HYSTERESIS".

11. THIS SECTION FOR GOVERNMENT USE ONLY

a. CHECK ONE

[X]EXISTING DOCUMENT SUPPLEMENTED [] REVISED DOCUMENT MUST BE [] CUSTODIAN OF MASTER DOCUMENT BY THIS NOR MAY BE USED IN RECEIVED BEFORE MANUFACTURER SHALL MAKE ABOVE REVISION AND MANUFACTURE. MAY INCORPORATE THIS CHANGE. FURNISH REVISED DOCUMENT TO:

b. ACTIVITY AUTHORIZED TO SIGNATURE AND TITLE DATE (YYMMDD)

APPROVE MICHAEL A. FRYE 93-04-07
CHANGE FOR GOVERNMENT BRANCH CHIEF
DESC-ECS

12. ACTIVITY ACCOMPLISHING
REVISION
DESC-ECS

REVISION COMPLETED (Signature)
RICK C. OFFICER
93-04-07

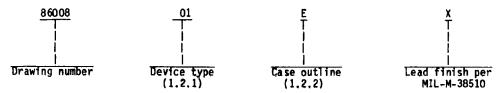
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DESC FORM 193-1 SEP 87

 \circ U.S. Government Printing Office: 1987 — 748-129/60912 $5962{-}E724$

1. SCOPE

- $1.1\,$ Scope. This drawing describes device requirements for class B microcircuits in accordance with $1.2.1\,$ of MIL-STD-883, "Provisions for the use of MIL-STD-883 in conjunction with compliant non-JAN devices".
 - 1.2 Part number. The complete part number shall be as shown in the following example:



1.2.1 Device types. The device types shall identify the circuit function as follows:

Device type	Generic number	Circuit	tpD*(at TA	= +25°C)
			Min	Max
01	685	Open-emitter output	4.5	6.5 ns
02	685	Open-emitter output	0.5	6.5 ns
03	6685	Open-emitter output	2.0	4.0 ns
04	96685	Open-emitter output	1.5	3.5 ns

1.2.2 <u>Case outlines</u>. The case outlines shall be as designated in appendix C of MIL-M-38510, and as follows:

Outline letter	Case outline
E	D-2 (16-lead, .840" X .310" X .200"), dual-in-line package
I	A-2 (10-lead, .370" X .185") can package
2	C-2 (20-terminal, .358" x .358" x .100"), square chip carrier package

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MILITARY	DRAWING

DEFENSE BLECTRONICS SUPPLY CENTER DAYTON, OHIO 45444

SIZE A			Ę	16008	
	R	EVISION LEVEL	-	SHEET	
	I		В		2

Positive supply voltage (V+):	1.3 Absolute maximum ratings.						
Device type 04	Positive supply voltage (V+):						
Negative supply voltage (Y-): Device type 04	Device types 01, 02, 03			- +7 V dc			
Device types 01, 02, 03	Negative supply voltage (V-):						4
Device type 04	Device types 01, 02, 03			7 V dc			
Differential input voltage (Yp):	Device type 04			6.5 V dc			
Differential input voltage (Yp):	Input voltage range (VI):			+4 V dc	•		
Differential input voltage (Yp):	Device type 04			- ±5 V dc			
Strappe temperature range -	Differential input voltage (VID):						
Storage temperature range	Device types 01, 02, 03	. 		- *6 V QC - *5 5 V dc			
Maximum power dissipation (Pp): Device types 03, 04	Storage temperature range			65°C to	+150°C		
Device types 03, 04 Lead temperature (soldering, 10 seconds) + 300 °C Thermal resistance, Junction-to-case (Q ₃ C): Cases E, 1, 2 See MIL-M-38510, appendix C Junction temperature (T ₁) - +175 °C Thermal resistance, Junction-co-ambient (Q ₃ A): Case E 120 °C/N Case I - 140 °C/N Case I - 140 °C/N Case I - 92,3 °C/N Output current - 30 mA 1.4 Recommended operating conditions. Positive supply voltage (V+): Device types 01, 02, 03 - +6.0 V dc Device type 04 +5.2 V dc Device types 01, 02, 035.2 V dc Device type 045.2 V dc Device type 045.2 V dc Rinimum operating temperature range (T _A)55 °C to +125 °C 2/ Minimum operating voltage (V+ to V-) 9.7 V dc Latch enable voltage: VIH	M - 1						
Lead temperature (soldering, 10 seconds) - +300°C Thermal resistance, junction-to-case (@jc):	Device types 01, 02			- 500 mW			
Thermal resistance, Junction-to-case (0JC): Case E, I, Z	Lead temperature (soldering, 10 seco	onds)		- +300°C			
Junction temperature (13) Thermal resistance, junction-to-ambient (0)A): Case E 120°C/M Case 2 - 92.3°C/M Output current - 30 mA 1.4 Recommended operating conditions. Positive supply voltage (V+): Device type 01, 02, 03 - +6.0 V dc Device type 04 +5.0 V dc Device type 01, 02, 035.2 V dc Device type 045.2 V dc Device type 01, 02, 035.2 V dc Device type 0455°C to +125°C 2/ Minimum operating temperature range (TA)55°C to +125°C 2/ Minimum operating voltage (V+ to V-) 9,7 V dc Latch enable voltage: VIH	Thermal variations dispution to once	. /^\.			20510	andšu č	
Thermal resistance, junction-to-ambient (0 ₁ A): Case E 120°C/W Case I 140°C/W Case I 92,3°C/W Output current 92,3°C/W Output current 30 mA 1.4 Recommended operating conditions. Positive supply voltage (V+): Device types 01, 02, 03 +6.0 V dc Device types 01, 02, 035.0 V dc Device types 01, 02, 035.2 V dc Device type 045.2 V dc Device type 04	Cases E, 1, 2	. 		- +175°C	-2021A' gbb	enaix C	
Case E	Thermal resistance, junction-to-ambi	ient (914)	:				
Case 2 92.3°C/N Output current 30 mA 1.4 Recommended operating conditions. Positive supply voltage (V+):	Case E			- 120°C/W			
Output current	Case I			- 140°C/W			
Positive supply voltage (V+): Device types 01, 02, 03	Output current			- 30 mA			
Positive supply voltage (Y+): Device types 01, 02, 03 +6.0 V dc Device type 04 +5.0 V dc 1/ Negative supply voltage (Y-): Device type 01, 02, 035.2 V dc Device type 045.2 V dc 1/ Ambient operating temperature range (TA)5.5°C to +125°C 2/ Minimum operating voltage (Y+ to Y-) 9,7 V dc Latch enable voltage: VIH	·						
Device types 01, 02, 03 +6.0 V dc Device type 04 +5.0 V dc Device types 01, 02, 03 5.0 V dc Device types 01, 02, 03 5.2 V dc Device type 04 5.2 V dc Device type 04 5.2 V dc Device type 04 5.2 V dc Minimum operating temperature range (TA) 5.2 V dc Latch enable voltage: VIH	1.4 Recommended operating conditions.						
Negative supply voltage (Y-): Device types 01, 02, 03 5.2 V dc Device type 04 5.2 V dc 1/ Ambient operating temperature range (T _A) 55°C to +125°C 2/ Minimum operating voltage (Y+ to V-) 9.7 V dc Latch enable voltage: VIH	Positive supply voltage (V+):						
Negative supply voltage (Y-): Device types 01, 02, 03 5.2 V dc Device type 04 5.2 V dc 1/ Ambient operating temperature range (T _A) 55°C to +125°C 2/ Minimum operating voltage (Y+ to V-) 9.7 V dc Latch enable voltage: VIH	Device types 01, 02, 03	·		- +6.0 V dc	1.1		
Device types 01, 02, 03 5.2 V dc Device type 04 5.2 V dc Ambient operating temperature range (TA) 5.5 °C to +175 °C 2/ Minimum operating voltage (V+ to V-) 9.7 V dc Latch enable voltage: VIH85 V VIL85 V VIL	Device type 04			- +5.0 V dc	1/		
Device type 04	Device types 01, 02, 03			5.2 V dc			
Minimum operating voltage (Y+ to Y-) 9.7 V dc Latch enable voltage: YIH85 V YIL65 V 1/7 V _{IN} < positive supply and negative supply voltage. 2/ Devices require a thermal equilibrium to be established with a transverse airflow of >500 LFPM. STANDARDIZED MILITARY DRAWING DEFENSE ELECTRONICS SUPPLY CENTER REVISION LEVEL SHEET	Device type 04			5.2 V dc	1/		
Latch enable voltage: VIH VIH VIL IN IN IN IN IN IN IN IN IN	Ambient operating temperature range	(IA)		-55 t to 1	125 C Z/		
T/V _{IN ≤} positive supply and negative supply voltage. 2/ Devices require a thermal equilibrium to be established with a transverse airflow of ≥500 LFPM. STANDARDIZED MILITARY DRAWING DEFENSE ELECTRONICS SUPPLY CENTER REVISION LEVEL SHEET	latch onable voltage:						
I/ V _{IN ≤} positive supply and negative supply voltage. 2/ Devices require a thermal equilibrium to be established with a transverse airflow of ≥500 LFPM. STANDARDIZED MILITARY DRAWING DEFENSE ELECTRONICS SUPPLY CENTER REVISION LEVEL SHEET	Уін			85 V			
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STANDARDIZED MILITARY DRAWING DEFENSE ELECTRONICS SUPPLY CENTER SIZE A 86008 REVISION LEVEL SHEET	1/ Vin < positive supply and negative sup	ply volta	ge.				
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2. APPLICABLE DOCUMENTS

2.1 Government specification and standard. Unless otherwise specified, the following specification and standard, of the issue listed in that issue of the Department of Defense Index of Specifications and Standards specified in the solicitation, form a part of this drawing to the extent specified herein.

SPECIFICATION

MILITARY

MIL-M-38510

- Microcircuits, General Specification for.

STANDARD

MILITARY

MIL-STD-883

- Test Methods and Procedures for Microelectronics.

(Copies of the specification and standard required by manufacturers in connection with specific acquisition functions should be obtained from the contracting activity or as directed by the contracting activity.)

2.2 Order of precedence. In the event of a conflict between the text of this drawing and the references cited herein, the text of this drawing shall take precedence.

3. REQUIREMENTS

- 3.1 Item requirements. The individual item requirements shall be in accordance with 1.2.1 of MIL-STD-883, "Provisions for the use of MIL-STD-883 in conjunction with compliant non-JAN devices" and as specified herein.
- 3.2 Design, construction, and physical dimensions. The design, construction, and physical dimensions shall be as specified in MIL-M-38510 and herein.
 - 3.2.1 Terminal connections. The terminal connections shall be as specified on figure 1.
 - 3.2.2 Case outlines. The case outlines shall be in accordance with 1.2.2 herein.
- 3.3 Electrical performance characteristics. Unless otherwise specified, the electrical performance characteristics are as specified in table I and apply over the full ambient operating temperature range.
- 3.4 Marking. Marking shall be in accordance with MIL-STD-883 (see 3.1 herein). The part shall be marked with the part number listed in 1.2 herein. In addition, the manufacturer's part number may also be marked as listed in 6.4 herein.
- 3.5 Certificate of compliance. A certificate of compliance shall be required from a manufacturer in order to be Tisted as an approved source of supply in 6.4. The certificate of compliance submitted to DESC-ECS prior to listing as an approved source of supply shall state that the manufacturer's product meets the requirements of MIL-STD-883 (see 3.1 herein) and the requirements herein.
- 3.6 Certificate of conformance. A certificate of conformance as required in MIL-STD-883 (see 3.1 herein) shall be provided with each lot of microcircuits delivered to this drawing.
- 3.7 Notification of change. Notification of change to DESC-ECS shall be required in accordance with MIL-STD-883 (see 3.1 herein).

STANDARDIZED MILITARY DRAWING	SiZE A	 	8	6008	
DEFENSE ELECTRONICS SUPPLY CENTER DAYTON, OHIO 45444		REVISION LEVEL	- B	SHEET	4

Test	 Symbol 			 Group A subgroups	Lim [.]	its	Uni
	! 	unless otherwise specified 1/2/3/4/	types 		Min	Max	
Input offset voltage	\v_10	R _S = 100Ω,	A11	1		±2.0	_ mV
	<u> </u>	V _{CM} = 0 V dc		2, 3		±3.0	
Input offset voltage	7Λ1 0 	R _S = 100Ω	01, 02	 1, 2, 3 		±10	μ V /
temperature coefficien <u>5</u> /	ΔΤ	V _{CM} = 0 V	03	<u> </u>		±15.0	F
	<u> </u>		04			±20	
Input offset current	110	! V _{CM} = 3.3 V T _A = +25 C	01, 02			±1.0	μА
	 		03	<u> </u>		±1.5	
		V _{CM} = +.5 V T _A = +25°C	04 1] 		±1.0	
		-V _{CM} = -3 ₆ 3 V T _A = +125 °C, -55 °C	01, 02	2, 3		±1.6	
	1		03	<u> </u>		±3.0	
	· .	-VCM =5 V T _A = +125°C, -55°C	 04 	 		 ±1.6 	
nput bias current	IIIB	Y _{CM} = 3.3 Y T _A = +25°C	01, 02	1		10	μ.Α
	 	T _A = +25°C	 03	T]		15	
·	 	V _{CM} = +.5 V T _A = +25°C	04		:	10 10	- :
	j - I	-V _{CM} = -3,3 V T _A = +125°C, -55°C	01, 02	2,3		16	
	 	T _A = +125°C, ~55°C	03	T]		30	- <u> </u>
ļ	 	 -V _{CM} =5 V T _A = +125°C, -55°C	l 04] 		 16 	

STANDARDIZED MILITARY DRAWING	SIZE A		8	6008	
DEFENSE ELECTRONICS SUPPLY CENTER DAYTON, OHIO 45444		REVISION LEVE	В	SHEET 5	·

	Symbol	Conditions -55°C < TA < +125°C unless otherwise specified	Device	Group A subgroups	Limits		Unit	
		unless otherwise specified $\frac{1}{2} \frac{2}{3} \frac{3}{4}$	types 		Min	Max		
Input voltage range	V _{CM}		01,02,03	1, 2, 3	-3.3	3.3	٧	
	1	 	04	- 	-2.5	+5.0		
Input voltage common mode rejection ratio	CMRR 	R _S = 100Ω, -3.3 V <u><</u> V _{CM} <u><</u> +3.3 V	01,02,03	4, 5, 6	80		dB	
	 	-2.5 <u><</u> V _{CM} <u><</u> +5.0 V	04] 	 		
Power supply rejection ratio	PSRR 	R _S = 100Ω, ΔV _S = ±5%	A11	4, 5, 6	60		dB	
High level output voltage	VOH	T _A = +25°C	01,02,03	1	 960 	810	V	
		T _A = +125°C	T ·	2	850	620	-	
		T _A = -55°C	Ţ	3	-1.10	920		
			04	1, 2, 3	-1.10		-	
Low level output voltage	V _{OL}	T _A = +25°C	01,02,03	1	-1.85	-1.65	٧	
		T _A = +125°C	Ţ	2	-1.81	-1.57	-	
		T _A = -55°C	Ţ	3	-1.91	-1.69	- 	
			04	1, 2, 3		-1.50		

TABLE	I. Elect	rical performance characteri	stics - Co	ontinued.		·	
Test	Symbol	Conditions -55°C < TA < +125°C unless otherwise specified 1/2/3/4/	Device	 Group A subgroups 	 Lim Min	its Max	 Unit
Positive supply current	I+]	01,02,03	1, 2, 3	 	22	l mA
Negative supply current	 I-		01, 02	1, 2, 3		-26 -18	l mA
Propagation delay time	t _{PD} ±	T _A = -55°C, +25°C <u>6</u> / <u>7</u> /	03, 04	9, 11	4.5	 	ns
	-	T _A = +125°C <u>6</u> / <u>7</u> /	 	10	5.5	12	<u>;</u>
	 	T _A = +25°C, -55°C <u>6</u> / <u>7</u> /	02	9, 11	0.5	6.5	Τ ! !
	; - 1 1	T _A = +125°C 6/ 7/	† 	10	0.5	1 12	Γ
	•	T _A = +25°C, -55°C <u>7</u> / <u>8</u> /	03	9, 11	1 2.0	1 4.0	T ! !
		T _A = +125°C <u>7/ 8/</u>	Ť I	10	 1.5 	6.0	T
	i - 	T _A = +25°C, -55°C <u>9</u> /	04	9, 11	1.5	3.5	T
		T _A = +125°C <u>9/</u>	T 	 10 	 1.5 	6.0	
Propagation delay time Latch enable to output	t _{PD} *	T _A = +25°C, -55°C	01, 03	9, 11		 8 	i ns
,		T _A = +125°C	[10 	 	12.5	
	 	T _A = +25°C, -55°C	 02 	9, 11	 	 8 	
	 	T _A = +125°C	 	10	 	112.5	<u> </u>
		T _A = +25°C,	04	 9 	 	3.5	
	 	T _A = +125°C, -55°C		10, 11	 	 7 	
See footnotes on top of ne	xt page.						
STANDARDIZ MILITARY DRA		SIZE A		86	800		
MILITARY DRA DEFENSE ELECTRONICS S DAYTON, OHIO 4	UPPLY CEN	TER REVI	REVISION LEVEL				

- For device types 01, 02, and 03 unless otherwise specified: $V^+ = +6.0 \text{ V}$ dc; $V_- = -5.2 \text{ V}$ dc; V_T = -2.0 V dc, and R_L = 50Ω .
- 2/ Devices require a thermal equilibrium to be established with a transverse airflow of >500 LFPM.
- 3/ Production pulse test devices at correlated temperatures of -35°C and +145°C to compensate for high power steady-state operation.
- 4/ For device type 04 unless otherwise specified: V+ = +5.0 Y dc; V- = -5.2 V dc; V_T = -2.0 V dc, and $R_L = 50\Omega$.
- 5/ Guaranteed if not tested to the limits specified.
- 6/ 100 mV step input with 5 mV overdrive.
- $\frac{7}{}$ a. This parameter tested with $V_{CM} = 0$ Y and supplies Y+ = 6.0 Y, V- = -5.2 V.
 - b. Only tp_D^+ on output Q. c. Only tp_D^- on output \overline{Q} .
- 8/ 100 mV step input with 10 mV overdrive V+ = +5.0 V; V- = -5.2 V for 03.
- 9/ This parameter measured with 100 mV pulse (10 mV overdrive), to 50 percent of the transition output point.

STANDARDIZED MILITARY DRAWING	SIZE A		8	6008	
DEFENSE ELECTRONICS SUPPLY CENTER DAYTON, OHIO 45444	_	MEVISION LEVEL	В	SHEET 8	

01, 02, 03, and 04 04 Device types 2 I E Case outlines Terminal number Terminal symbol NC ٧+ GROUND 1 1 GROUND 1 2 NONINVERTING INPUT 3 INVERTING INPUT NONINVERTING INPUT INVERTING INPUT NONINVERTING INPUT LATCH ENABLE ٧-5 NC INVERTING INPUT NC LATCH ENABLE NC NC 7 Q OUTPUT NC LATCH ENABLE 8 Q OUTPUT ٧ -9 GROUND 2 NC NC ٧-10 GROUND 1 NC Q OUTPUT 11 NC **Q** OUTPUT NC 12 13 NC NC Q OUTPUT 14 Q OUTPUT NC 15 GROUND 2 NC 16 17 NC 18 NC NC 19 GROUND 2 20

NC = no connection

FIGURE 1. Terminal connections.

STANDARDIZED MILITARY DRAWING	SIZE A		86008	
DEFENSE ELECTRONICS SUPPLY CENTER DAYTON, OHIO 45444		REVISION LEVE	В	SHEET 9

DESC FORM 193A SEP 87

- 3.8 Verification and review. DESC, DESC's agent, and the acquiring activity retain the option to review the manufacturer's facility and applicable required documentation. Offshore documentation shall be made available onshore at the option of the reviewer.
 - 4. OUALITY ASSURANCE PROVISIONS
- 4.1 Sampling and inspection. Sampling and inspection procedures shall be in accordance with section 4 of MIL-M-38510 to the extent specified in MIL-STD-883 (see 3.1 herein).
- 4.2 Screening. Screening shall be in accordance with method 5004 of MIL-STD-883, and shall be conducted on all devices prior to quality conformance inspection. The following additional criteria shall apply:
 - a. Burn-in test, method 1015 of MIL-STD-883 .
 - (1) Test condition A. B. C. or D using the circuit submitted with the certificate of compliance (see 3.5 herein).
 - (2) $T_A = +125$ °C, minimum.
 - b. Interim and final electrical test parameters shall be as specified in table II herein, except interim electrical parameter tests prior to burn-in are optional at the discretion of the manufacturer.
- 4.3 Quality conformance inspection. Quality conformance inspection shall be in accordance with method 5005 of MIL-STD-883 including groups A, B, C, and D inspections. The following additional criteria shall apply.
 - 4.3.1 Group A inspection.
 - a. Tests shall be as specified in table II herein.
 - b. Subgroups 7 and 8 in table I, method 5005 of MIL-STD-883 shall be omitted.
 - 4.3.2 Groups C and D inspections.
 - a. End-point electrical parameters shall be as specified in table II herein.
 - b. Steady-state life test conditions, method 1005 of MIL-STD-883.
 - (1) Test condition A, B, C, or D using the circuit submitted with the certificate of compliance (see 3.5 herein).
 - (2) $T_A = +125^{\circ}C$, minimum.
 - (3) Test duration: 1,000 hours, except as permitted by method 1005 of MIL-STD-883.

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TABLE II. Electrical test requirements.

MIL-STD-883 test requirements	Subgroups (per method 5005, table I)
 Interim electrical parameters (method 5004) 	
 Final electrical test parameters (method 5004) 	1*, 2, 3, 4
Group A test requirements (method 5005)	1, 2, 3, 4, 5, 1 6, 9, 10, 11**
 Groups C and D end-point electrical parameters (method 5005)	1

PDA applies to subgroup 1.
 ** Subgroups 10 and 11, if not tested, shall be guaranteed to the specified limits in table I.

5. PACKAGING

5.1 Packaging requirements. The requirements for packaging shall be in accordance with MIL-M-38510.

6. NOTES

- 6.1 Intended use. Microcircuits conforming to this drawing are intended for use when military specifications do not exist and qualified military devices that will perform the required function are not available for OEM application. When a military specification exists and the product covered by this drawing has been qualified for listing on QPL-38510, the device specified herein will be inactivated and will not be used for new design. The QPL-38510 product shall be the preferred item for all applications.
- 6.2 Replaceability. Microcircuits covered by this drawing will replace the same generic device covered by a contractor-prepared specification or drawing.
- 6.3 Comments. Comments on this drawing should be directed to DESC-ECS, Dayton, Ohio 45444, or telephone 513-296-5375.

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6.4 Approved sources of supply. Approved sources of supply are listed herein. Additional sources will be added as they become available. The vendors listed herein have agreed to this drawing and a certificate of compliance (see 3.5 herein) has been submitted to DESC-ECS.

 Military drawing part number	Vendor CAGE number	Vendor similar part number 1/
8600801EX	34335 64155	AM685/BEA LT685J/883
8600801IX	34335 64155	AM685/BIC LT685H/883
8600802EX	64155	LT685J/883
8600802IX	64155	LT685H/883
8600803EX	34335	AM6685/BEA
86008031X	34335	AM6685/BIC
8600804EX	3 403 1	AD96685TQ/883B
8600804IX	34031	AD96685TH/883B
86008042X	34031	AD96685TE/883B

 $[\]frac{1}{\text{Caution.}} \ \, \text{Do not use this number for item} \\ \frac{\text{acquisition.}}{\text{acquisition.}} \ \, \text{Items acquired to this number may} \\ \text{not satisfy the performance requirements} \\ \text{of this drawing.}$

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Vendor CAGE
numberVendor name
and address34031Analog Devices, Incorporated
Computer Labs Division
7910 Triad Center Drive
Greensboro, NC 2740934335Advanced Micro Devices, Incorporated
901 Thompson Place
P.O. Box 3453
Sunnyvale, CA 9408864155Linear Technology Corp.
1630 McCarthy Blvd.
Milpitas, CA 95035-7487

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<u>.</u>	- -1	Document No.:
86008 10. DESCRI	PTION OF REVISION - CONTINUED	Revision: C
		NOR No.:
5962-R054-93		Sheet: 2
of 2		
Sheet 11	: TABLE II. Delete the second sentence at the bottom of table and subs	titute the following;
	"** Subgroups 9, 10, and 11, if not tested, shall be guaranteed to	the limits in table I
herein."	Revision level block; add "C".	
Sheet	12: 6.4. Approved sources of supply. Under military drawing part	numbers 8600803EX and
8600803IX,	delete vendor CAGE number 34335 and substitute footnote " $2/$ ". Foo	tnote <u>2</u> / states, "Not
available	from an approved source of supply".	
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